

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S167	1420	((gate near metal) (gate near polysilicon))near5 (gate near dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/14 19:47
S168	2	((gate near metal) (gate near polysilicon))near5 (gate near dielectric)) same anode same cathode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/14 19:49
S169	2	S168 and (@ad<"20040827" @rlad<"20040827")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/14 19:49
S170	11	((gate near metal) (gate near polysilicon))near5 (gate near dielectric)) same (gate near voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/14 19:49
S171	10	S170 and (@ad<"20040827" @rlad<"20040827")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/14 19:49